

III B. Tech II Semester Supplementary Examinations, November – 2019

MICROWAVE ENGINEERING

(Electronics and Communication Engineering)

Time: 3 hours

Max. Marks: 70

- Note: 1. Question Paper consists of two parts (**Part-A** and **Part-B**)
 2. Answer **ALL** the question in **Part-A**
 3. Answer any **FOUR** Questions from **Part-B**

PART –A**(14 Marks)**

1. a) Define cut-off frequency of a waveguide and write its significance. [2M]
- b) Draw the schematic diagram of a microstrip line. [2M]
- c) Define reentrant cavity. [2M]
- d) Write the applications of magnetron. [3M]
- e) Write short notes on waveguide irises. [3M]
- f) Write the performance characteristics of TRAPATT diode. [2M]

PART –B**(56 Marks)**

2. a) What are the characteristics and advantages of microwaves? Explain. [7M]
- b) What are the various power losses in waveguides? Explain. [7M]
3. Discuss about TE modes in circular waveguides. [14M]
4. a) Draw the diagram of two-cavity klystron amplifier and explain its working. [7M]
- b) Explain about limitations of conventional tubes at microwave frequencies. [7M]
5. a) What is meant by slow wave structure? List out the various slow wave structures. [7M]
- b) Discuss the properties of Helical slow wave structure. [7M]
6. a) Discuss about power output and efficiency of cylindrical magnetron. [7M]
- b) What is S-matrix? Explain its significance and write the properties of S-matrix. [7M]
7. a) Explain the operation of circulator and write its applications. [7M]
- b) Explain about RWH theory for Gunn effect. [7M]
- c) Explain the procedure of measurement of low VSWR. [7M]
